Revision 1.00

### GAIN CHIPS AR coated Fabry-Perot Laser

General	Product	Information
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### Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T <sub>c</sub>	°C	0		20
Forward Current	١ <sub>F</sub>	mA			160
Reverse Voltage	V <sub>R</sub>	V			0
Output Power (extracavity)	P <sub>opt</sub>	mW			30

#### **Recommended Operational Conditions**

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T <sub>C</sub>	°C			20
Forward Current	١ <sub>F</sub>	mA			160

### Characteristics at T<sub>C</sub>= at 20°C, BOL under recommended working condition, with external cavity

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm		655	
Tuning Range	$\Delta\lambda_{tun}$	nm	650		660
Output Power	P <sub>opt</sub>	mW		20	
Polarization				TE	
Spatial Mode (transversal)				TEM00	

#### Measurement Conditions / Comments

Stess in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

#### Measurement Conditions / Comments

Measurement Conditions / Comments The actual achieved wavelength and power are strongly influenced by the external cavity. eyP gives no guarantee on these parameters.

E field parallel to Pin 2 - Pin 3 - plane Fundamental Mode

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without external cavity	ssion (ASE)				
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>ASE</sub>	µA/mW	1		40
Chin Parameter					
Chip Parameter					
Chip Parameter Parameter	Symbol	Unit	min	typ	max
	Symbol L	Unit µm	min	<b>typ</b> 2000	max

Measurement Conditions / Comments U<sub>R MD</sub> = 5 V Measurement Conditions / Comments



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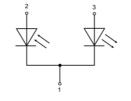
# GAIN CHIPS AR coated Fabry-Perot Laser

Package Dimensions					
Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h	mm	3.50	3.65	3.70
Excentricity of Emission Center	R	mm			0.12
Pin Length	L <sub>PIN</sub>	mm		14	
i in Length	-PIN			14	

### Measurement Conditions / Comments reference plane: top side of TO header reference: center of outer diameter of header

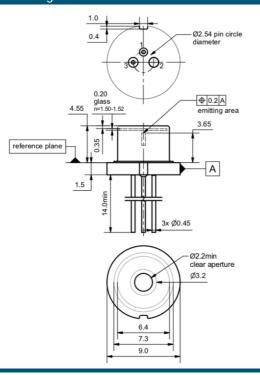
### Package Pinout

- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode





### Package Drawings





#### AIZ-16-0421-1517

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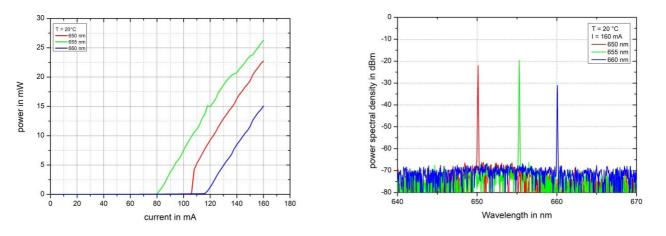


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### GAIN CHIPS AR coated Fabry-Perot Laser

#### Typical Measurement Results



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPA diode type is known to be sensitive against thermal stress. It should not be operated without appropriate injection from a seed laser. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode. The chip should be protected against moisture. A water vapor content below 5000 ppm is recommended for applications with high reliability requirements.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

VISIBLE LASER RADIATION VISIBLE LASER RADIATION VISIBLE LASER RADIATION DURCT OR SCATTERED RADIATION

CLASS 4 LASER PRODUCT WAVELENGTH 655 nm MAX\_OUTPUT POWER 30 mV

IEC-60825-0



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